NSN 5961-00-581-2960

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-581-2960 **Inclosure Material:** Metal **Overall Length:** 0.255 inches **Overall Diameter:** 0.265 inches **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 180.0 reverse voltage, peak **Current Rating Per Characteristic:** 30.00 milliamperes repetitive peak forward current **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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